

120V NPN HIGH VOLTAGE DARLINGTON TRANSISTOR
Features

- $BV_{CEO} > 120V$
- Low Saturation Voltage $< 1.5V @ 1A$
- Darlington Transistor $h_{FE} > 2k @ 1A$
- $I_C = 1A$ High Continuous Collector Current
- Specification is Also Available in Eline and SOT223 Package Outlines
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

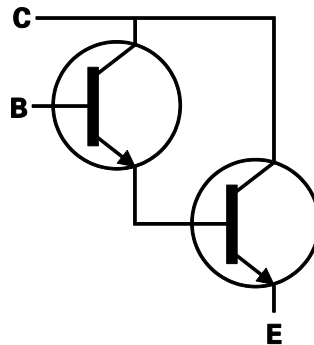
- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound
UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.052 grams (Approximate)

Applications

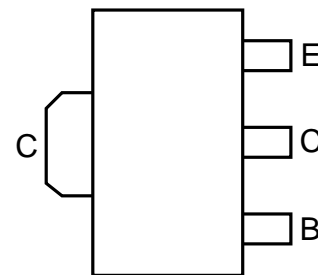
- Various Driving Functions
 - Lamps
 - Motors
 - Relays and Solenoids
- High Output Current Switches



Top View



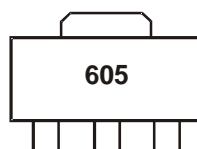
Device Symbol


 Top View
Pin-Out

Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FCX605TA	AEC-Q101	605	7	12	1,000

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain $< 900ppm$ bromine, $< 900ppm$ chlorine ($< 1500ppm$ total Br + Cl) and $< 1000ppm$ antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information


605 = Product Type Marking Code

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	140	V
Collector-Emitter Voltage	V _{CEO}	120	V
Emitter-Base Voltage	V _{EBO}	10	V
Continuous Collector Current	I _C	1	A
Peak Pulse Current	I _{CM}	4	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

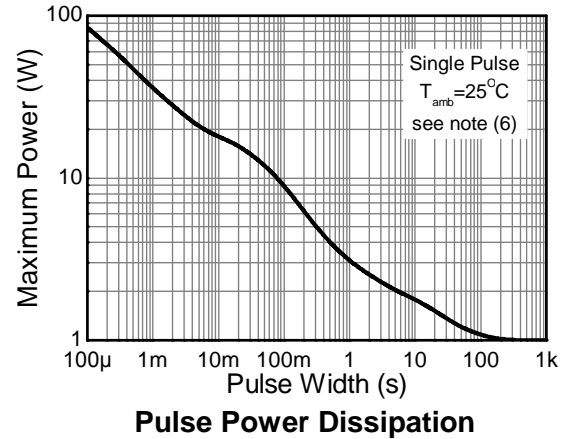
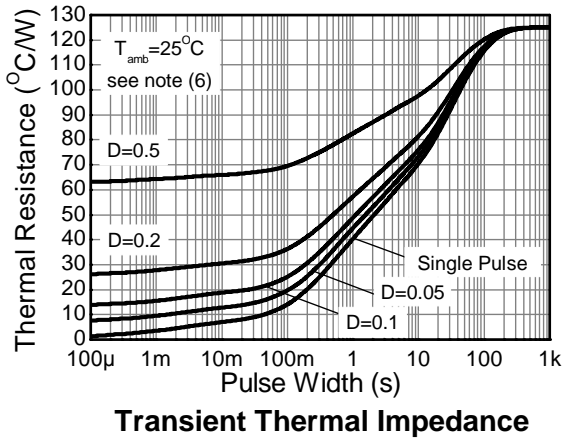
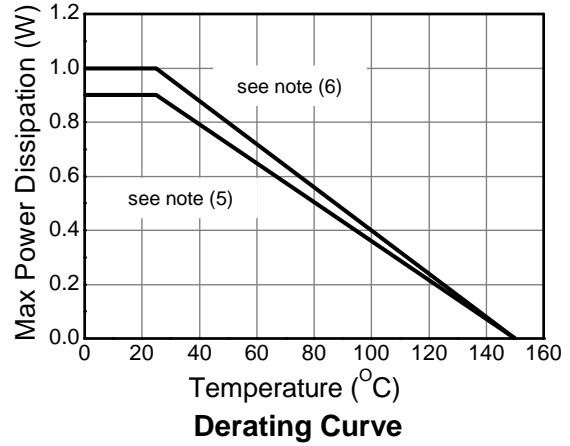
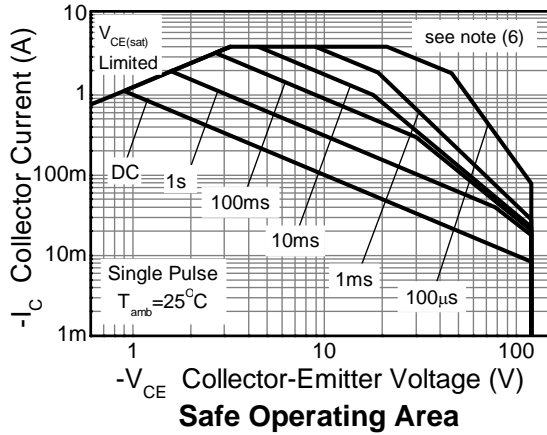
Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	(Note 5) 0.9	W
		(Note 6) 1	
Thermal Resistance, Junction to Ambient	R _{θJA}	(Note 5) 139	°C/W
		(Note 6) 125	
Thermal Resistance, Junction to Leads	R _{θJL}	5.2	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	2,000	V	2
Electrostatic Discharge - Machine Model	ESD MM	200	V	B

- Notes:
5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 6. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
 7. Thermal resistance from junction to solder-point (at the end of the leads).
 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information

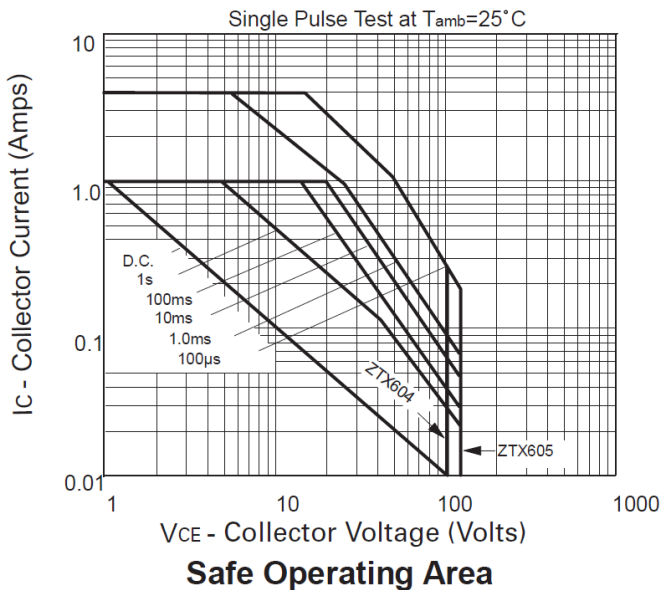
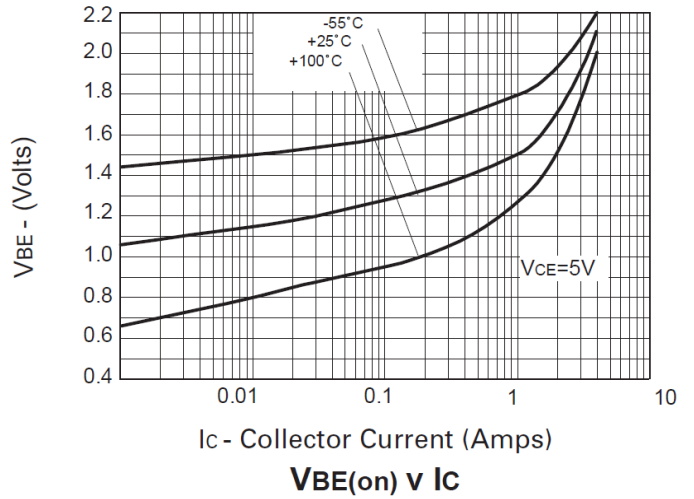
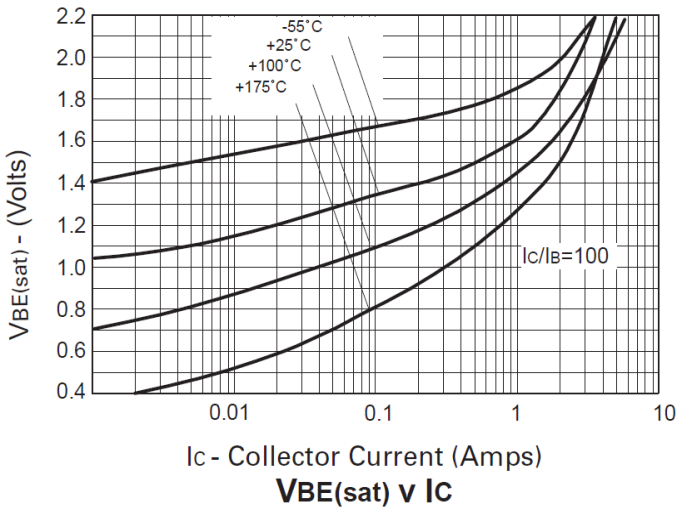
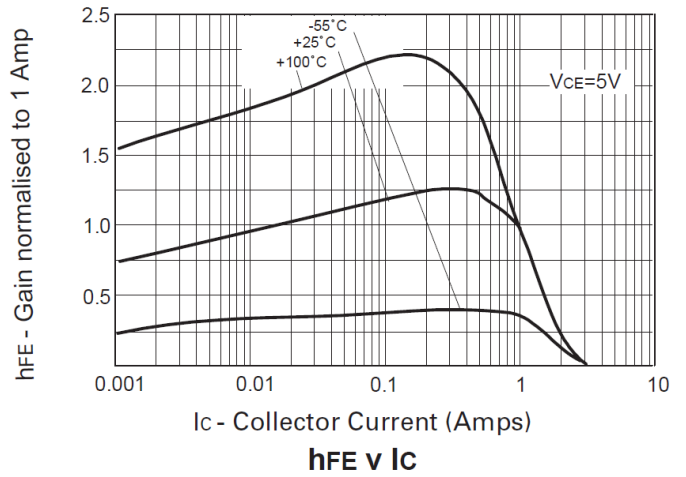
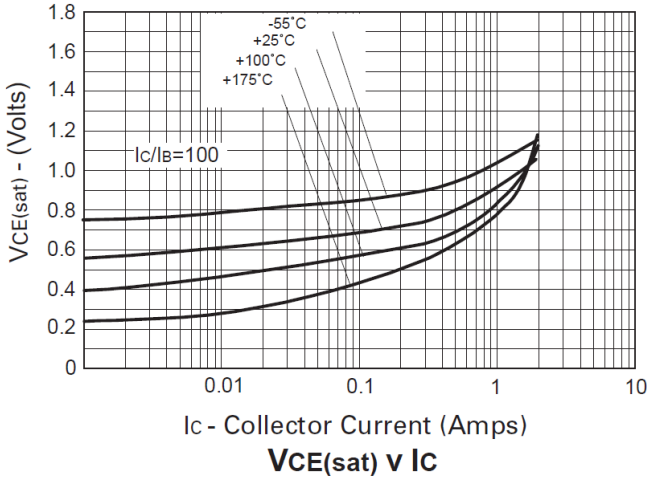


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV _{CBO}	140	—	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	120	—	—	V	I _{CEO} = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	10	—	—	V	I _{EBO} = 100μA
Collector Cut-off Current	I _{CBO}	—	—	100 10	nA μA	V _{CB} = 10V V _{CB} = 120V, T _A = +100°C
Emitter-base Cut-off Current	I _{EBO}	—	—	0.1	μA	V _{EB} = 8V
Collector Emitter Cut-Off Current	I _{CES}	—	—	10	μA	V _{CES} = 120V
ON CHARACTERISTICS (Note 9)						
Static Forward Current Transfer Ratio	h _{FE}	2k 5k 2k 0.5	— — — —	— — 100k —	—	I _C = 50mA, V _{CE} = 5V I _C = 500mA, V _{CE} = 5V I _C = 1A, V _{CE} = 5V I _C = 2A, V _{CE} = 5V
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	—	—	1 1.5	V	I _C = 250mA, I _B = 0.25mA I _C = 1A, I _B = 1mA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	—	—	1.8	V	I _C = 1A, I _B = 1mA
Base-Emitter Turn-On Voltage	V _{BE(ON)}	—	—	1.7	V	I _C = 1A, V _{CE} = 5V
SMALL SIGNAL CHARACTERISTICS (Note 9)						
Transition Frequency	f _T	150	—	—	MHz	I _C = 100mA, V _{CE} = 10V f = 20MHz
Input Capacitance	C _{ibo}	—	90	—	pF	V _{CB} = 500mV, f = 1MHz
Output Capacitance	C _{obo}	—	15	—	pF	V _{CB} = 10V, f = 1MHz
Turn-On Time	t _{ON}	—	0.5	—	μs	I _C = 500mA, V _{CE} = 10V I _{B1} = -I _{B2} = 0.5mA
Turn-Off Time	t _{OFF}	—	1.6	—	μs	I _C = 500mA, V _{CE} = 10V I _{B1} = -I _{B2} = 0.5mA

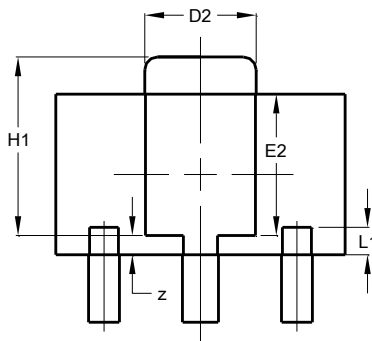
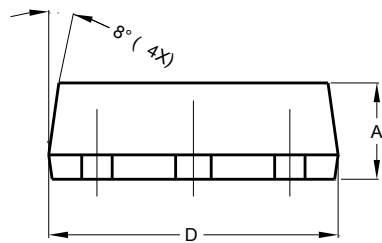
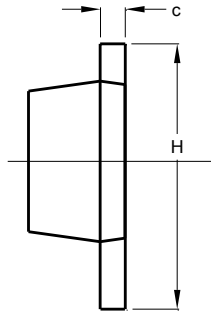
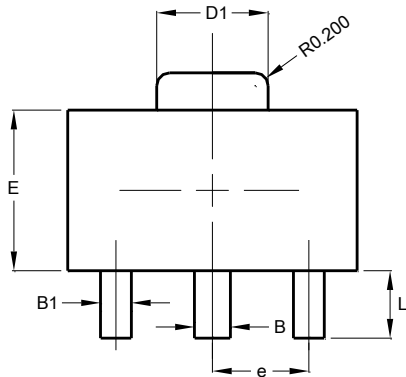
Note: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Package Outline Dimensions

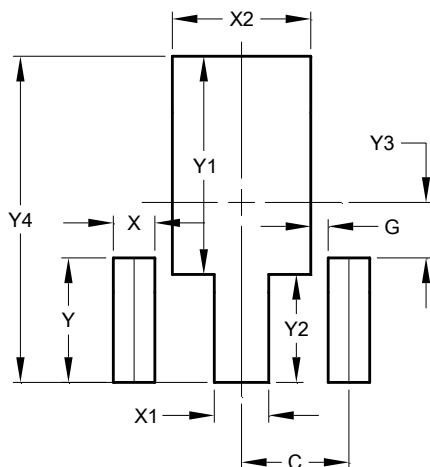
Please see <http://www.diodes.com/package-outlines.html> for the latest version.



SOT89			
Dim	Min	Max	Typ
A	1.40	1.60	1.50
B	0.50	0.62	0.56
B1	0.42	0.54	0.48
c	0.35	0.43	0.38
D	4.40	4.60	4.50
D1	1.62	1.83	1.733
D2	1.61	1.81	1.71
E	2.40	2.60	2.50
E2	2.05	2.35	2.20
e	-	-	1.50
H	3.95	4.25	4.10
H1	2.63	2.93	2.78
L	0.90	1.20	1.05
L1	0.327	0.527	0.427
z	0.20	0.40	0.30
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.



Dimensions	Value (in mm)
C	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Y	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.

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